



60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D T _C = +25°C
-60V	110mΩ @ V _{GS} = -10V	-14A
	140mΩ @ $V_{GS} = -4.5V$	-12A

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

- DC-DC Converters
- Power Management Functions
- Analog Switch

Features and Benefits

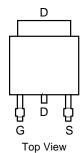
- Low On-Resistance
- Low Input Capacitance
- Totally Lead-Free & Fully RoHS Compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

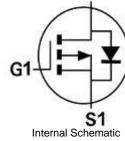
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (\$\frac{1}{2}\$)
- Weight: 0.33 grams (Approximate)









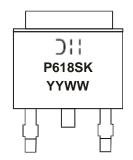
Ordering Information (Note 5)

Part Number	Case	Packaging
DMP6180SK3Q-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to http://www.diodes.com/product_compliance_definitions.html
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



Oll = Manufacturer's Marking
NH4011SS = Product Type Marking Code
YYWW = Date Code Marking
YY = Year (ex: 16 = 2016)
WW = Week (01 - 53)



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	-60	V
Gate-Source Voltage			V _{GSS}	±20	V
Continuous Drain Current (Note 7) V _{GS} = -10V	Steady State	$T_{C} = +25^{\circ}C$ $T_{C} = +100^{\circ}C$	I _D	-14 -10	А
Maximum Body Diode Forward Current (Note 7)			Is	4.1	Α
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)			I_{DM}	25	Α

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Units
Total Bower Discinction (Note 6)	T _A = +25°C	Ь	1.7	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	P_D	1.0	
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D- · ·	76	°C/W
Thermal Resistance, Junction to Ambient (Note o)	T < 10s	$R_{\theta JA}$	33	
Total Power Dissipation (Note 7)	$T_A = +25$ °C	Pn	2.7	W
Total Fower Dissipation (Note 1)	$T_A = +70^{\circ}C$	PD	1.5	
Thermal Resistance, Junction to Ambient (Note 7)	Steady State	D	50	°C/W
Thermal Resistance, Junction to Ambient (Note 1)	t < 10s	$R_{\theta JA}$	24	
Total Power Dissipation (Note 7)	$T_C = +25^{\circ}C$	Ъ	40	W
Total Fower Dissipation (Note 7)	$T_{C} = +100^{\circ}C$	P_{D}	16	VV
Thermal Resistance, Junction to Case (Note 7)	Steady State	R _{0JC}	3.1	°C/W
Operating and Storage Temperature Range		T_J,T_STG	-55 to +150	°C

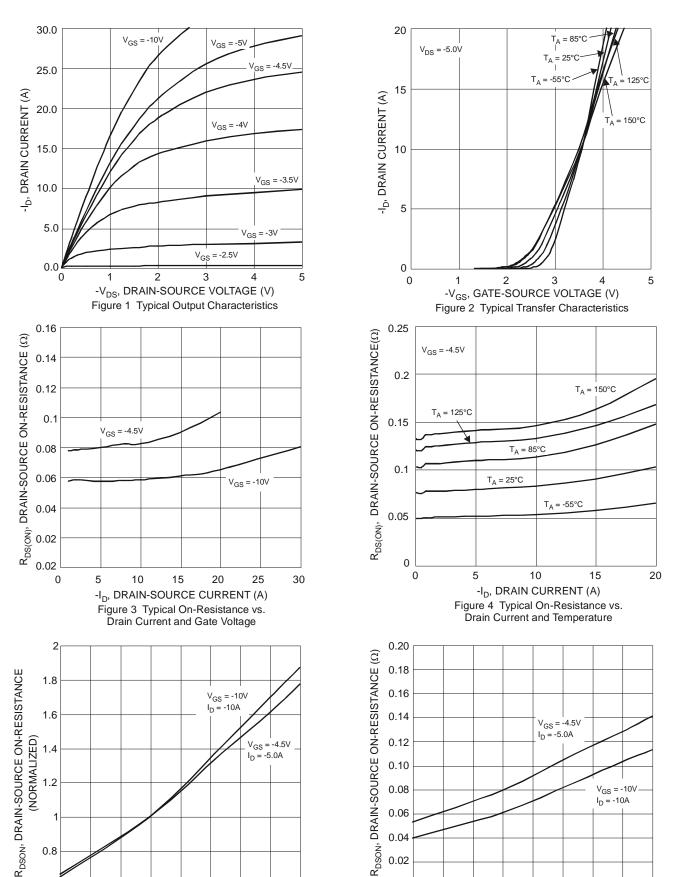
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)							
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -48V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)	ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	-1.2	_	-2.7	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	
Static Drain-Source On-Resistance			60	110	mΩ	$V_{GS} = -10V, I_D = -12A$	
Static Drain-Source Off-Resistance	R _{DS(ON)}		80	140	11177	$V_{GS} = -4.5V, I_D = -8A$	
Forward Transfer Admittance	Y _{FS}		15	_	S	$V_{DS} = -5V, I_{D} = -12A$	
Diode Forward Voltage	V_{SD}		-0.7	-1.0	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{ISS}	_	984.7	_			
Output Capacitance	Coss	_	58	_	pF	$V_{DS} = -30V$, $V_{GS} = 0V$, $f = 1.0MHz$	
Reverse Transfer Capacitance	C _{RSS}	_	45.5	_			
Gate Resistance	R_{G}		12.9	_	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -4.5V)	Q_{G}		8.1	_			
Total Gate Charge (V _{GS} = -10V)	Q _G	_	17.1	_	nC	$V_{DS} = -30V, I_{D} = -12A$	
Gate-Source Charge	Q _{GS}	_	3.2	_	IIC		
Gate-Drain Charge	Q_{GD}	_	3.9	_			
Turn-On Delay Time	t _{D(ON)}	_	5.9	_		V_{GS} = -10V, V_{DS} = -30V, R_{GEN} = 3 Ω , R_L = 2.5 Ω	
Turn-On Rise Time	t _R	_	21.2				
Turn-Off Delay Time	t _{D(OFF)}	_	30.9	_	ns		
Turn-Off Fall Time	t _F		39.1	_			
Body Diode Reverse Recovery Time	t _{RR}	_	19.9		ns	I _S = -12A, dI/dt = 100A/μs	
Body Diode Reverse Recovery Charge	Q_{RR}		1.7		nC	$I_S = -12A$, $dI/dt = 100A/\mu s$	

Notes:

- 6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
- 7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper pad layout.
- 8. Short duration pulse test used to minimize self-heating effect
- 9. Guaranteed by design. Not subject to production testing





 $\label{eq:TJ} \textbf{J}, \textbf{JUNCTION TEMPERATURE (°C)}$ Figure 6 On-Resistance Variation with Temperature

50

75

100

125

25

25

50

T_J, JUNCTION TEMPERATURE (°C)

Figure 5 On-Resistance Variation with Temperature

75

100

125

0.6

-50



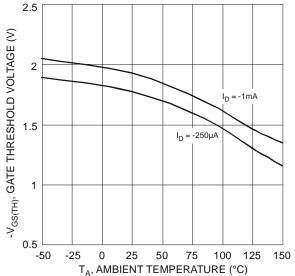
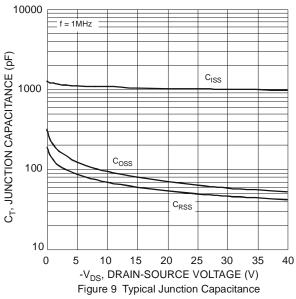
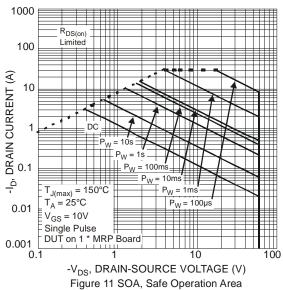
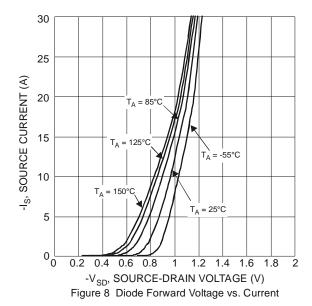
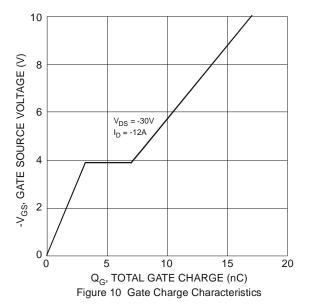


Figure 7 Gate Threshold Variation vs. Ambient Temperature

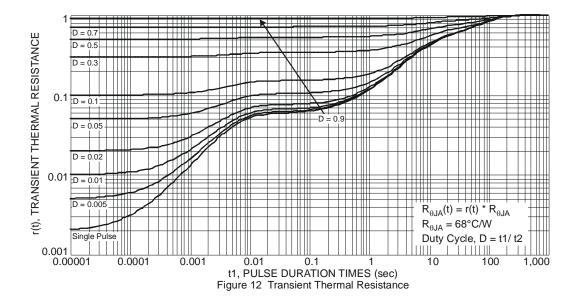








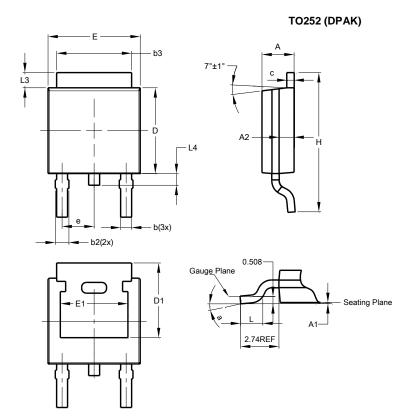






Package Outline Dimensions

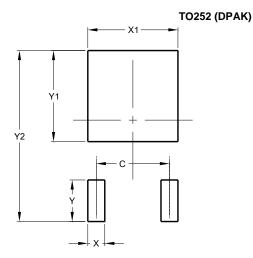
Please see http://www.diodes.com/package-outlines.html for the latest version.



TO252 (DPAK)					
Dim	Min	Max	Тур		
Α	2.19	2.39	2.29		
A 1	0.00	0.13	0.08		
A2	0.97	1.17	1.07		
b	0.64	0.88	0.783		
b2	0.76	1.14	0.95		
b3	5.21	5.46	5.33		
С	0.45	0.58	0.531		
D	6.00	6.20	6.10		
D1	5.21	-	-		
е	-	-	2.286		
Е	6.45	6.70	6.58		
E1	4.32	-	-		
Н	9.40	10.41	9.91		
Г	1.40	1.78	1.59		
L3	0.88	1.27	1.08		
L4	0.64	1.02	0.83		
а	0°	10°	-		
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)			
С	4.572			
X	1.060			
X1	5.632			
Y	2.600			
Y1	5.700			
Y2	10.700			



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